

Microscopic Bardeen-Cooper-Schrieffer formulation of the critical temperature of multilayer copper-oxide superconductors

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(Dated: Received 22 October 2009 / In final form 8 December 2009)

We study superconductivity in multilayer copper oxides, in the frame of a realistic microscopic formulation. Solving the full temperature dependent BCS gap equations, we obtain a maximum in the transition temperature T_c for $M=3$ or 4 CuO_2 layers in the unit cell for appropriate values of the interlayer tunneling (negative pair tunneling), and via the consideration of the doping imbalance between the inner and outer layers. This is the ubiquitous experimental result for Ca intercalated copper oxides, as opposed to other intercalating elements. Further, using a restricted set of parameters, we obtain an exact fit of $T_c(M=1-4)$ for five different Ca intercalated homologous copper oxide families.

PACS numbers: 74.72.-h, 74.20.Fg, 74.62.-c, 74.78.Fk

A long standing puzzle of the high transition temperature T_c cuprate superconductors is the dependence of T_c on the number M of CuO_2 layers in the unit cell. Experiments show ubiquitously that within any Ca intercalated homologous cuprate family, i.e. for materials sharing the same charge reservoir block but having varying M (here Ca is between the layers), T_c is maximum for $M=3$ - a summary of experiments appears in e.g. [1] - with the $M=4$ exception of the $\text{Ti}_2\text{Ba}_2\text{Ca}_{M-1}\text{Cu}_M\text{O}_{2M+3+\delta}$ family [2], following a dome-type dependence on M . That is at optimum doping for any M . As mentioned in [3], other spacing elements, such as Y, Ba and Sr yield lower T_c for the multilayer materials compared to the single layer material. Setting aside the central issue of superconductivity within a single CuO_2 layer, the issue of what determines T_c in a multilayer system is a very important one. Inter alia, it points to the role of out-of-plane mechanisms and to how T_c can be maximized for any given cuprate family.

This issue has been treated in a number of theoretical papers, as in [1, 4–10], with limited success. E.g. in ref. [1] a Bardeen-Cooper-Schrieffer (BCS) model (different from ours) was considered, and a saturating increase of T_c as a function of $M=1-\infty$ was obtained. In ref. [10] the dome with a maximum for $M=3$ was obtained for the superconducting order parameter (not directly for T_c itself) in the frame of a Landau-Ginzburg functional treatment, and by appealing to the putative ddw order parameter.

The cuprates fall into the realm of strong correlations, thus calling for an Eliashberg-type treatment [11–13]. Given the lack of a definitive theory for the single CuO_2 layer superconducting state, our BCS treatment is a decent attempt towards the understanding of the multilayer cuprates. We hereby consider a realistic microscopic model in the frame of the BCS formulation [14], which does yield the experimental fact of the maximum T_c for $M=3$ or 4 for a range of the parameters considered. That is for moderately small single particle and pair tunneling between successive CuO_2 layers. As experiments indicate that T_c decreases steadily for $M>3$ (with the aforementioned exception), we content ourselves with calculating T_c for the cases $M=1-4$, assuming that the trends found also apply for $M>4$. The complex calculations required for $M>4$ are out of the scope of the present paper.

We consider the BCS-type Hamiltonian for M CuO_2 layers in the unit cell

$$H = \sum_{i,k,\sigma} \varepsilon_{i,k} d_{i,k,\sigma}^\dagger d_{i,k,\sigma} + \sum_{i,k,p} V_i(k,p) d_{i,k,\uparrow}^\dagger d_{i,-k,\downarrow}^\dagger d_{i,-p,\downarrow} d_{i,p,\uparrow} \quad (1)$$

$$+ \sum_{\langle il \rangle, k, \sigma} t_{\perp,k} d_{i,k,\sigma}^\dagger d_{l,k,\sigma} + \sum_{\langle il \rangle, k} T_k d_{i,k,\uparrow}^\dagger d_{i,-k,\downarrow}^\dagger d_{l,-k,\downarrow} d_{l,k,\uparrow} .$$

The creation/annihilation operators $d_{i,k,\sigma}^\dagger/d_{i,k,\sigma}$ describe electrons in the i -th CuO_2 layer in the unit cell, interacting via $V_i(k,p)$, and $i=1-M$. $\varepsilon_{i,k} = \epsilon_{i,k} - \mu_i$, with the dispersion $\epsilon_{i,k} = -2t_i(\cos k_x + \cos k_y) - 4t'_i \cos k_x \cos k_y - 2t''_i(\cos 2k_x + \cos 2k_y)$, $k_x, k_y = [-\pi, \pi]$, and the chemical potential μ_i of the i -th layer. The (in-plane momentum conserving) coupling between successive neighbor CuO_2 layers $\langle il \rangle$ for single electron tunneling is [15]

$$t_{\perp,k} = t_o(\cos k_x - \cos k_y)^2 , \quad (2)$$

while for pair tunneling is (proportional to $t_{\perp,k}^2$, e.g. c.f.[6] and below)

$$T_k = T_o(\cos k_x - \cos k_y)^4 . \quad (3)$$

We diagonalize the single particle kinetic energy part of the Hamiltonian. The original operators $d_{i,k,\sigma}$ are given in terms of the new ones $c_{i,k,\sigma}$ as $\vec{d}_M = U_M \vec{c}_M$, $\vec{d}_M = (d_{1,k,\sigma}, d_{2,k,\sigma}, \dots, d_{M,k,\sigma})$ [16]. In the new basis, we consider variational BCS states of the type

$$|\Psi\rangle = \prod_{i,k} (u_{i,k} + v_{i,k} c_{i,k,\uparrow}^\dagger c_{i,-k,\downarrow}^\dagger) |0\rangle, \quad (4)$$

with $u_{i,k}, v_{i,k}$ the well known coherence factors.

For M=2 layers $c_{1,2} = (d_1 \pm d_2)/\sqrt{2}$, and the transformed Hamiltonian is

$$\begin{aligned} H = & \sum_{i,k,\sigma} \xi_{i,k} c_{i,k,\sigma}^\dagger c_{i,k,\sigma} + \frac{1}{2} \sum_{k,p} V(k,p) [c_{1,k,\uparrow}^\dagger c_{1,-k,\downarrow}^\dagger c_{1,-p,\downarrow} c_{1,p,\uparrow} + c_{1,k,\uparrow}^\dagger c_{1,-k,\downarrow}^\dagger c_{2,-p,\downarrow} c_{2,p,\uparrow} + (1 \leftrightarrow 2)] \\ & + \frac{1}{2} \sum_k T_k [c_{1,k,\uparrow}^\dagger c_{1,-k,\downarrow}^\dagger c_{1,-k,\downarrow} c_{1,k,\uparrow} + c_{1,k,\uparrow}^\dagger c_{1,-k,\downarrow}^\dagger c_{2,-k,\downarrow} c_{2,k,\uparrow} + (1 \leftrightarrow 2)] . \end{aligned} \quad (5)$$

Here $\xi_{1,k} = \varepsilon_k - t_{\perp,k}$, $\xi_{2,k} = \varepsilon_k + t_{\perp,k}$ correspond to the bonding and antibonding states. The two initial layers are equivalent, and hence $V_1 = V_2 = V$. We also made use of the fact that the only non-zero matrix elements with four operators $c_{i,k,\sigma}$ ($\langle O \rangle = \langle \Psi | O | \Psi \rangle$) are - c.f. ref. [14] and below for $u_{i,k}, v_{i,k}$ and $f_{i,k}$

$$\langle c_{i,k,\uparrow}^\dagger c_{i,-k,\downarrow}^\dagger c_{j,-p,\downarrow} c_{j,p,\uparrow} \rangle = v_{i,k} u_{i,k} v_{j,p} u_{j,p} (1 - 2f_{i,k})(1 - 2f_{j,p}) . \quad (6)$$

Bearing in mind that $u_{i,k}^2 + v_{i,k}^2 = 1$, $0 \leq u_{i,k}^2, v_{i,k}^2 \leq 1$, we treat the coherence factors as $u_{i,k} = \cos(\theta_{i,k})$, $v_{i,k} = \sin(\theta_{i,k})$. Minimizing $\langle H \rangle = \langle \Psi | H | \Psi \rangle$ with respect to $\theta_{i,k}$ yields the gap equations

$$0 = -2 \xi_{i,k} v_{i,k} u_{i,k} + \Delta_{i,k} [u_{i,k}^2 - v_{i,k}^2] , \quad (7)$$

while minimizing $\langle F = H - TS \rangle$, with the entropy $S = -2 \sum_{i,k} [f_{i,k} \ln f_{i,k} + (1 - f_{i,k}) \ln(1 - f_{i,k})]$ and the temperature $T = 1/\beta$, with respect to the thermal factors $f_{i,k}$ yields

$$f_{i,k} = \frac{1}{1 + e^{\beta E_{i,k}}} , \quad E_{i,k} = \frac{\xi_{i,k}}{u_{i,k}^2 - v_{i,k}^2} . \quad (8)$$

The gaps $\Delta_{i,k}$ are a sum of a diagonal (in the layer index i) part $G_{i,k}$ and a non-diagonal part $g_{i,k}$.

$$\begin{aligned} \Delta_{i,k} &= G_{i,k} + g_{i,k} , \quad G_{i,k} = -\frac{1}{2} \sum_p V(k,p) v_{i,p} u_{i,p} \tanh(\beta E_{i,p}/2) - \frac{1}{2} T_k v_{i,k} u_{i,k} \tanh(\beta E_{i,k}/2) , \\ g_{i,k} &= -\frac{1}{2} \sum_p V(k,p) v_{j,p} u_{j,p} \tanh(\beta E_{j,p}/2) - \frac{1}{2} T_k v_{j,k} u_{j,k} \tanh(\beta E_{j,k}/2) , \quad (i,j) = \{(1,2), (2,1)\} . \end{aligned} \quad (9)$$

Here $\Delta_{1,k} = \Delta_{2,k}$. We note that setting $i = j$ and $T_k = t_{\perp,k} = 0$ reduces these equations to the usual gap equation $0 = -2 \xi_k v_k u_k + \Delta_k [u_k^2 - v_k^2]$, with $\Delta_k = -\sum_p V(k,p) v_p u_p \tanh(\beta E_p/2)$ and $E_k = \sqrt{\xi_k^2 + \Delta_k^2} = \xi_k / (u_k^2 - v_k^2)$. But, note that we do *not* enforce a relation of the type $E_{i,k} \sim \sqrt{\Delta_{i,k}^2 + \xi_{i,k}^2}$ for M>1.

The general form of the transformed Hamiltonian is

$$H = \sum_{i,k,\sigma} \xi_{i,k} c_{i,k,\sigma}^\dagger c_{i,k,\sigma} + \sum_{i,j; k,p} w_{ij}(k,p) c_{i,k,\uparrow}^\dagger c_{i,-k,\downarrow}^\dagger c_{j,-p,\downarrow} c_{j,p,\uparrow} . \quad (10)$$

The coefficients $w_{ji}(k,p)$ are determined below. Thus we obtain as above the gap equations for $u_{i,k}, v_{i,k}, f_{i,k}$ in the general form (7),(8), but now with

$$G_{i,k} = -\sum_p w_{ii}(k,p) v_{i,p} u_{i,p} \tanh(\beta E_{i,p}/2) , \quad g_{i,k} = -\frac{1}{2} \sum_{j \neq i; p} [w_{ij}(k,p) + w_{ji}(k,p)] v_{j,p} u_{j,p} \tanh(\beta E_{j,p}/2) . \quad (11)$$

For M=3 layers, $\xi_{1,k} = \varepsilon_{1,k}$, $\xi_{(2,3),k} = (\varepsilon_{1,k} + \varepsilon_{2,k} \mp d)/2$, with $d = \sqrt{a^2 + 8t_{\perp,k}^2}$, $a = \varepsilon_{1,k} - \varepsilon_{2,k}$. Also

$$w_{ij}(k,p) = V_1(k,p) [A_{ij}^{(1)}(k,p) + A_{ij}^{(3)}(k,p)] + V_2(k,p) A_{ij}^{(2)}(k,p) + E_{ij}(k) \delta_{kp} . \quad (12)$$

The terms $A_{ij}^{(m)}$ correspond to the initial layers $m=1-3$, with layers 1 and 3 being equivalent: $\varepsilon_{1,k} = \varepsilon_{3,k}$. We have

$$\begin{aligned} A_{ij}^{(1)}(k, p) &= A_{ij}^{(3)}(k, p) = b_i^2(k)b_j^2(p) \quad , \quad A_{ij}^{(2)}(k, p) = g_i^2(k)g_j^2(p) \quad , \\ E_{ij}(k) &= 2T_k [b_i^2(k)g_j^2(k) + b_j^2(k)g_i^2(k)] \quad , \end{aligned} \quad (13)$$

with $b_1(k) = 1/\sqrt{2}$, $b_2(k) = (1 - a/d)u_1/4$, $b_3(k) = (1 + a/d)u_2/4$, $g_1(k) = 0$, $g_2(k) = t_{\perp,k}u_1/d$, $g_3(k) = t_{\perp,k}u_2/d$ and $u_1 = \sqrt{2 + (a + d)^2/(2t_{\perp,k})^2}$, $u_2 = \sqrt{2 + (a - d)^2/(2t_{\perp,k})^2}$.

For M=4 layers $\xi_{(1,2),k} = (\varepsilon_{1,k} + \varepsilon_{2,k} + t_{\perp,k} \mp s_1)/2$, $\xi_{(3,4),k} = (\varepsilon_{1,k} + \varepsilon_{2,k} - t_{\perp,k} \mp s_2)/2$, with $d = \varepsilon_{1,k} - \varepsilon_{2,k}$, $s_{1,2} = \sqrt{d^2 \pm 2 t_{\perp,k} d + 5 t_{\perp,k}^2}$. Here

$$w_{ij}(k, p) = V_1(k, p)[A_{ij}^{(1)}(k, p) + A_{ij}^{(4)}(k, p)] + V_2(k, p)[A_{ij}^{(2)}(k, p) + A_{ij}^{(3)}(k, p)] + E_{ij}(k) \delta_{kp} \quad . \quad (14)$$

The terms $A_{ij}^{(m)}$ correspond to the initial layers 1-4, with layers 1 and 4 and also 2 and 3 being equivalent. Now

$$\begin{aligned} A_{ij}^{(1)}(k, p) &= A_{ij}^{(4)}(k, p) = b_i^2(k)b_j^2(p) \quad , \quad A_{ij}^{(2)}(k, p) = A_{ij}^{(3)}(k, p) = g_i^2(k)g_j^2(p) \quad , \\ E_{ij}(k) &= 2T_k [b_i^2(k)g_j^2(k) + b_j^2(k)g_i^2(k) + g_i^2(k)g_j^2(k)] \quad , \end{aligned} \quad (15)$$

with $b_1(k) = u_1(d + t_{\perp,k} - s_1)/(4s_1)$, $b_2(k) = u_2(d + t_{\perp,k} + s_1)/(4s_1)$, $b_3(k) = u_3(-d + t_{\perp,k} + s_2)/(4s_2)$, $b_4(k) = u_4(d - t_{\perp,k} + s_2)/(4s_2)$, $g_1(k) = u_1 t_{\perp,k}/(2s_1)$, $g_2(k) = u_2 t_{\perp,k}/(2s_1)$, $g_3(k) = u_3 t_{\perp,k}/(2s_2)$, $g_4(k) = u_4 t_{\perp,k}/(2s_2)$ and $u_1 = \sqrt{2 + (d + t_{\perp,k} + s_1)^2/(2t_{\perp,k}^2)}$, $u_2 = \sqrt{2 + (d + t_{\perp,k} - s_1)^2/(2t_{\perp,k}^2)}$, $u_3 = \sqrt{2 + (d - t_{\perp,k} + s_2)^2/(2t_{\perp,k}^2)}$, $u_4 = \sqrt{2 + (d - t_{\perp,k} - s_2)^2/(2t_{\perp,k}^2)}$.

So far the formalism was quite generic. Specializing to Coulomb repulsion generated positive definite pairing potentials [12] for the cuprates, we consider the realistic non-separable form (and thus harder computationally)

$$V_i(\vec{k}, \vec{p}) = V_i(\vec{k} - \vec{p}) \quad , \quad V_i(\vec{q}) = V_{oi} \sin^2(q_x a) \sin^2(q_y a) \quad , \quad V_{oi} > 0 \quad , \quad (16)$$

which is peaked at (near) $\vec{Q} = (\pm\pi, \pm\pi)$ for $a = 0.5$ ($0.5 < a < 0.6$). This type of potential is well known to generate a $d_{x^2-y^2}$ -wave gap [11, 12].

Another relevant issue is the doping imbalance for M>2 layers in the unit cell. Namely, NMR experiments show that the outer layers are overdoped with holes compared to the inner layers [17], in agreement with earlier theoretical estimates [5]. We account for this fact by typically considering $\mu_{out} = \mu - 0.06t$, $\mu_{in} = \mu + 0.06t$ for both M=3,4, with μ_{out}/μ_{in} referring to the chemical potentials of the original outer/inner layers and μ the chemical potential for the case M=1,2. Assuming a screened electronic interaction, its strength is determined by the susceptibility $\chi(q, \omega)$ [12, 13]. It can be shown that $\chi(q, \omega = 0)$ is a decreasing function of μ for the range of doping considered herein [12]. Therefore, taking $V_{o1} = V_{o,out} > V_{o2} = V_{o,in}$, reflects also the effect of $\mu_{out} < \mu_{in}$ for M=3,4. In our model, this potential imbalance is more important than the sheer μ imbalance. Overall, $V_i(k, p)$ and T_k (c.f. below) mostly determine the gaps $\Delta_{i,k}$ and hence T_c . This simply reflects the fact that both $V_i(k, p)$ and T_k enter on an equal basis in the BCS gap equations - c.f. eqs. (9) and (11). The potential has a drastic influence on T_c , as is known from standard BCS-Eliashberg theory [11, 12].

We give a summary of a few calculations in the 3 figures and the table below, noting that they refer to $d_{x^2-y^2}$ -wave solutions of the gap equations above [18]. In all cases the energy scale is given by $t = 1$, and $a = 0.5$. Typically values $0.5 < a < 0.6$ yield higher T_c 's, without a qualitative change of the results below.

In the table, an asterisk marks the highest T_c in each case. A maximum T_c for M=3, without resorting to the potential imbalance $V_{o,out} > V_{o,in}$ ($V_1 > V_2$ etc.), can be obtained for a small enough (in magnitude) pair hopping $T_o < 0$, and this fact is facilitated by smaller values of t_o - c.f. case A.1 and the figures. Otherwise, for $V_{o,out} = V_{o,in}$ and higher T_o , M=2 yields the maximum T_c . T_c depends weakly on the single particle hopping t_o . In ref. [8] it was shown that the bare value of t_o is significantly reduced through the effect of interactions. The sign of t_o is irrelevant, as can be seen from the gap equations. This is not the case for the sign of the pair-coherent term T_o though (c.f. below). $T_o > 0$, *in general*, does not reproduce the dome-type dependence of T_c on M with a maximum for M=3.

Given the strong dependence of T_c on T_k within our model, materials with Y, Ba and Sr intercalants should have a much smaller T_k than Ca-intercalated cuprates. Moreover, the in-plane pairing potential is expected to be weaker for the former materials for M>1.

In all, we note that the experimental situation of the T_c increasing for M=1-3 (or 4) and then dropping, is only realized for rather *small negative* values of the pair tunneling amplitude T_o . E.g. for $T_o = -0.02t$ M=2 yields

A. $t' = -0.35, t'' = 0, n = 0.80, T_o = -0.002$			
1.	$t_o = 0.001$	$V_{o1} = V_{o2} = 4$	$T_c(M = 1 - 4) = (5.384, 6.347, *6.424, 6.241)10^{-2}$
2.	$t_o = 0.01$	$V_{o1} = V_{o2} = 4$	$T_c(M = 1 - 4) = (5.384, *6.347, 6.187, 5.852)10^{-2}$
3.	$t_o = 0.001$	$V_{o1} = V_{o2} = 3$	$T_c(M = 1 - 4) = (1.960, *2.943, 2.806, 2.611)10^{-2}$
3.a	$t_o = 0.001$	$V_{o1} = 3.2, V_{o2} = 3$	$T_c(M = 3, 4) = (*3.403, 3.240)10^{-2}$
3.b	$t_o = 0.001$	$V_{o1} = 3.5, V_{o2} = 3$	$T_c(M = 3, 4) = (*4.406, 4.282)10^{-2}$
B. $t' = -0.35, t'' = 0, n = 0.80, T_o = -0.02$			
1.	$t_o = 0.001$	$V_{o1} = 4.5, V_{o2} = 4$	$T_c(M = 1 - 4) = (5.384, *14.68, 13.02, 9.870)10^{-2}$
C. $t' = -0.3, t'' = 0.2, n = 0.85, T_o = -0.002$			
1.	$t_o = 0.001$	$V_{o1} = V_{o2} = 4$	$T_c(M = 1 - 4) = (1.215, *1.700, 1.595, 1.546)10^{-2}$
1.a.	$t_o = 0.001$	$V_{o1} = 4.5, V_{o2} = 4$	$T_c(M = 3, 4) = (*2.264, 2.216)10^{-2}$
2.	$t_o = 0.01$	$V_{o1} = V_{o2} = 4$	$T_c(M = 1 - 4) = (1.215, *1.632, 1.382, 0.9957)10^{-2}$
2.a.	$t_o = 0.01$	$V_{o1} = 4.5, V_{o2} = 4$	$T_c(M = 3, 4) = (*1.978, 1.627)10^{-2}$

TABLE I: T_c calculated as a function of the parameters shown.

the maximum T_c , as opposed to $M=3$ for $T_o = -0.002t$ - c.f. case D.3 below for a maximum for $M=4$. The negative T_k can be understood as follows. Within the frame of second order perturbation theory, we have the relation $T_{il,k} = -2t_{\perp,k}^{(0)} v_{i,k}^{(0)} u_{i,k}^{(0)} v_{l,k}^{(0)} u_{l,k}^{(0)} / (E_{i,k}^{(0)} + E_{l,k}^{(0)})$, with the index (0) denoting the initial *uncoupled* layers, with $E_{i,k}^{(0)} = \sqrt{(\Delta_{i,k}^{(0)})^2 + \varepsilon_{i,k}^2}$. $T_{il,k} < 0$ follows from $E_{i,k}^{(0)} + E_{l,k}^{(0)} > 0$.

We give the results of our calculations for five homologous series of cuprates, which are similar to the cases above. We use a restricted set of parameters - $t = 220 - 245$ meV, $t' = -0.35t$, $t'' = 0$, $t_o = 0.03t$, $n = 0.80$, which corresponds to optimal doping, $a = 0.5$, $T_o = -0.0044t - (-0.0018)t$, and $V_{oi} = 2.7t - 4.2t$ - to demonstrate the fitting capacity of our model. We obtain exact matches with the experimental T_c values, given in degrees K and taken from ref. [1]. We also give the ratios $R = \max\{\Delta_{i,k}(T = 0)\}/T_c$, which turn out to be in the range 0.71-1. These values are too small compared to the actual experimental ones, pointing to the limitations of the BCS description for the cuprates. Along the same line, the V_{oi} values are in the intermediate coupling regime, i.e. beyond the strict limit of applicability of the BCS framework. Note that the opposite potential imbalance $V_1 < V_2$ would yield the same T_c 's with somewhat higher values of V_2 for $M=3,4$ than the V_1 values below. The values of t and V_{o1} are adjusted so as to yield $T_c(M=1)$. Then, T_o is chosen so as to yield $T_c(M=2)$. Subsequently, $V_{o2}(M = 3, 4) = V_{o1}(M = 1) = V_{o1}(M = 2)$, and $V_{o1}(M = 3, 4)$ are chosen so as to yield $T_c(M=3,4)$.

D.1 $\text{Bi}_2\text{Sr}_2\text{Ca}_{M-1}\text{Cu}_M\text{O}_{2M+4+\delta}$ with $t = 245$ meV and $T_o = -0.0044t$, $V_{o1} = V_{o2} = 2.7t$. For $M=3$ we take $V_{o1} = 3.5t$, thus obtaining $T_c(M=1-3)=36, 90, 110$ K and $R(M=1-3)=0.769, 0.713, 0.867$.

D.2 $\text{TlBa}_2\text{Ca}_{M-1}\text{Cu}_M\text{O}_{2M+3+\delta}$ with $t = 229$ meV and $T_o = -0.0044t$, $V_{o1} = V_{o2} = 3t$. For $M=3$ we take $V_{o1} = 3.85t$ and for $M=4$ $V_{o1} = 4.16t$, thus obtaining $T_c(M=1-4)=52, 107, 133, 127$ K and $R(M=1-4)=0.765, 0.781, 0.973, 1.034$.

D.3 $\text{Tl}_2\text{Ba}_2\text{Ca}_{M-1}\text{Cu}_M\text{O}_{2M+3+\delta}$ with $t = 220$ meV and $T_o = -0.0024t$, $V_{o1} = V_{o2} = 3t$. For $M=3$ we take $V_{o1} = 3.67t$ and for $M=4$ $V_{o1} = 4.2t$, thus obtaining $T_c(M=1-4)=50, 80, 110, 122$ K and $R(M=1-4)=0.765, 0.755, 0.909, 1.039$. This series has maximum T_c for $M=4$ - c.f. [2].

D.4 $\text{Tl}_2\text{Ba}_2\text{Ca}_{M-1}\text{Cu}_M\text{O}_{2M+4+\delta}$ with $t = 221$ meV and $T_o = -0.0018t$, $V_{o1} = V_{o2} = 3.5t$. For $M=3$ we take $V_{o1} = 3.76t$ and for $M=4$ $V_{o1} = 3.83t$, thus obtaining $T_c(M=1-4)=90, 115, 125, 116$ K and $R(M=1-4)=0.795, 0.845, 0.934, 0.976$.

D.5 $\text{HgBa}_2\text{Ca}_{M-1}\text{Cu}_M\text{O}_{2M+2+\delta}$ with $t = 238.5$ meV and $T_o = -0.0021t$, $V_{o1} = V_{o2} = 3.5t$. For $M=3$ we take $V_{o1} = 3.75t$ and for $M=4$ $V_{o1} = 3.89t$, thus obtaining $T_c(M=1-4)=97, 127, 135, 129$ K and $R(M=1-4)=0.765, 0.851, 0.932, 0.979$.

In summary, higher T_c in multilayer copper oxides arises from a relatively increased (in magnitude) pair interlayer coupling $T_k < 0$, combined with a substantial strength of the repulsive Coulomb interaction between the electrons. It seems that all these ingredients are present in the Ca-intercalated materials. This picture should possibly be complemented by the CuO_2 lattice symmetry effects [19]. The BCS approach, though of limited applicability in the cuprates, offers relevant insight. We give an interpretation of the negative T_k in the BCS framework.

Stamatis Stamatiadis provided essential programming assistance. The author enjoyed discussions with Josheph Betouras, who also read critically the manuscript. Funding received from the Dept. of Materials Science of the

University of Crete is acknowledged.

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$$U_3 = \begin{pmatrix} -b_1(k) & b_2(k) & b_3(k) \\ g_1(k) & -g_2(k) & g_3(k) \\ b_1(k) & b_2(k) & b_3(k) \end{pmatrix}, \quad U_4 = \begin{pmatrix} b_1(k) & -b_2(k) & b_3(k) & b_4(k) \\ g_1(k) & -g_2(k) & g_3(k) & g_4(k) \\ -g_1(k) & g_2(k) & g_3(k) & g_4(k) \\ -b_1(k) & b_2(k) & b_3(k) & b_4(k) \end{pmatrix}, \quad (17)$$

with $b_i(k), g_i(k)$ as given after eqs. (13) and (15) respectively.

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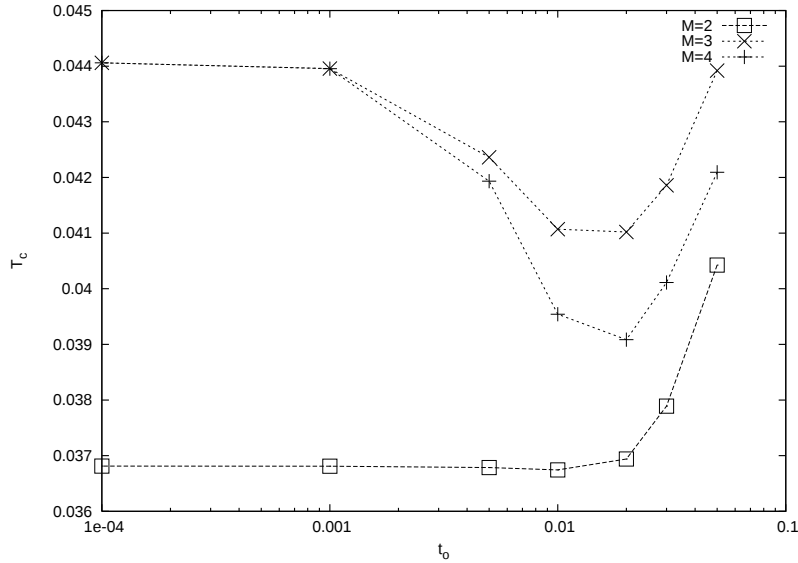


FIG. 1: T_c (in units of t) as a function of interplane hopping for $n = 0.85$, $t' = -0.35$, $t'' = 0$, $V_{o1} = V_{o2} = 4$. The inner/outer layer doping imbalance is taken into account for M=3,4. Squares : M=2, x's : M=3 and crosses : M=4. T_c versus t_o is shown for $T_o = 0$. All lines are guides to the eye.

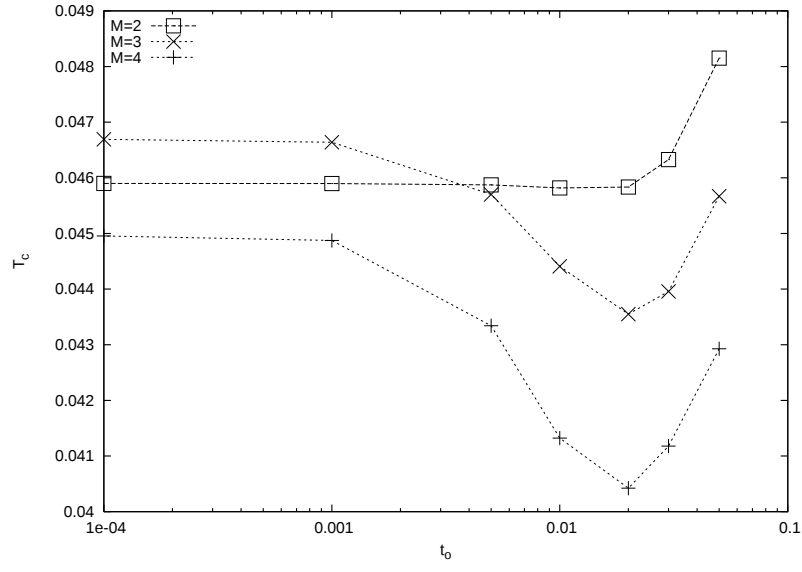


FIG. 2: Same as in fig. 1. T_c versus t_o for $T_o = -0.002$.

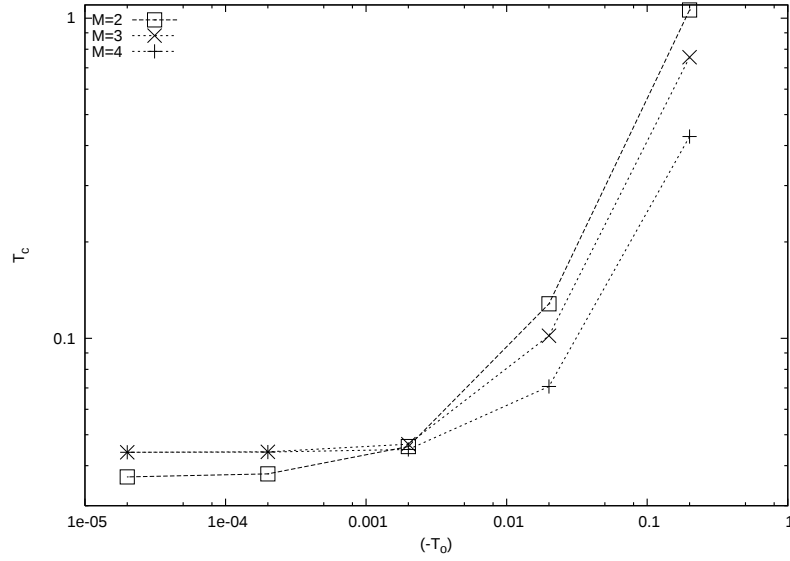


FIG. 3: Same as in fig. 1. T_c versus $(-T_o)$ for $t_o = 10^{-7}$. Notice the log scale for T_c .